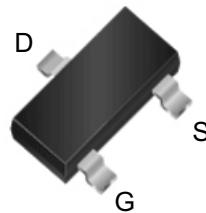


WPM3020

Single P-Channel, -30V, -3.8A, Power MOSFET

[Http://www.sh-willsemi.com](http://www.sh-willsemi.com)

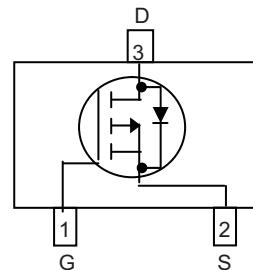
V_{DS} (V)	Typical R_{DS(on)} (mΩ)
-30	43 @ V _{GS} =-10V
	48 @ V _{GS} =-4.5V



Descriptions

The WPM3020 is P-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. This device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product WPM3020 is Pb-free.

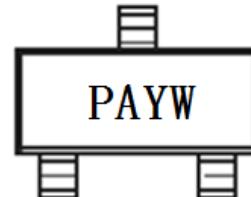
SOT-23



Pin configuration (Top view)

Features

- Trench Technology
- Supper high density cell design
- Excellent ON resistance
- Extremely Low Threshold Voltage
- Small package SOT-23



PA = Device Code
 Y = Year
 W = Week(A~z)

Applications

Marking

- DC/DC converters
- Power supply converters circuit
- Load/Power Switching for portable device

Order information

Device	Package	Shipping
WPM3020-3/TR	SOT-23	3000/Tape&Reel

Absolute Maximum ratings

Parameter	Symbol	10 s	Steady State	Unit
Drain-Source Voltage	V _{DS}	-30	±12	V
Gate-Source Voltage	V _{GS}	±12		
Continuous Drain Current ^{a d}	I _D	-3.8	-3.2	A
T _A =25°C		-3.0	-2.5	
Maximum Power Dissipation ^{a d}	P _D	1.2	0.9	W
T _A =70°C		0.8	0.5	
Continuous Drain Current ^{b d}	I _D	-3.0	-2.8	A
T _A =25°C		-2.4	-2.2	
Maximum Power Dissipation ^{b d}	P _D	0.8	0.7	W
T _A =70°C		0.5	0.4	
Pulsed Drain Current ^c	I _{DM}	-15		A
Operating Junction Temperature	T _J	-55 to 150		°C
Lead Temperature	T _L	260		°C
Storage Temperature Range	T _{stg}	-55 to 150		°C

Thermal resistance ratings

Single Operation					
Parameter	Symbol	Typical	Maximum	Unit	
Junction-to-Ambient Thermal Resistance ^a	t ≤ 10 s	R _{θJA}	84	102	°C/W
	Steady State		120	145	
Junction-to-Ambient Thermal Resistance ^b	t ≤ 10 s	R _{θJA}	130	160	°C/W
	Steady State		145	190	
Junction-to-Case Thermal Resistance	Steady State	R _{θJC}	60	75	

a Surface mounted on FR4 Board using 1 square inch pad size, 1oz copper

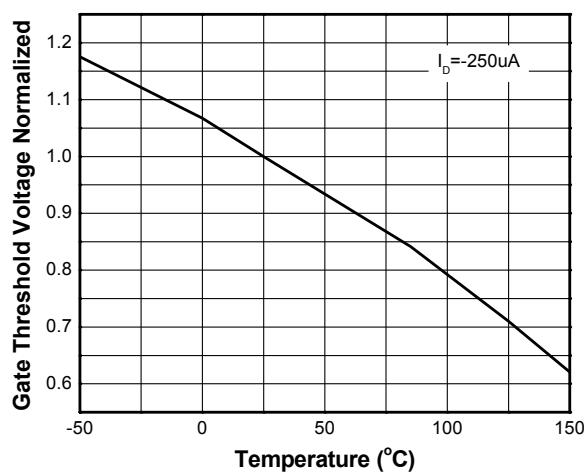
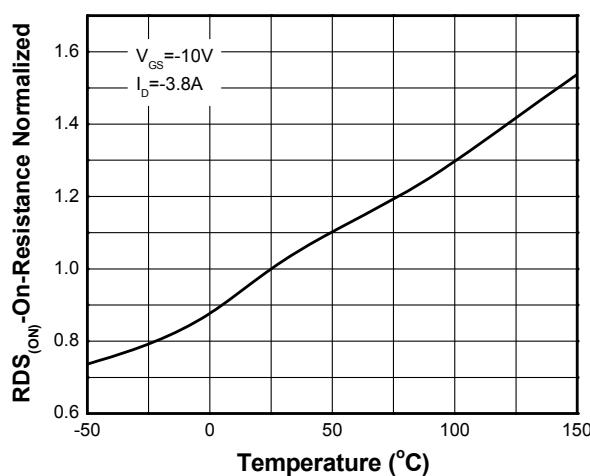
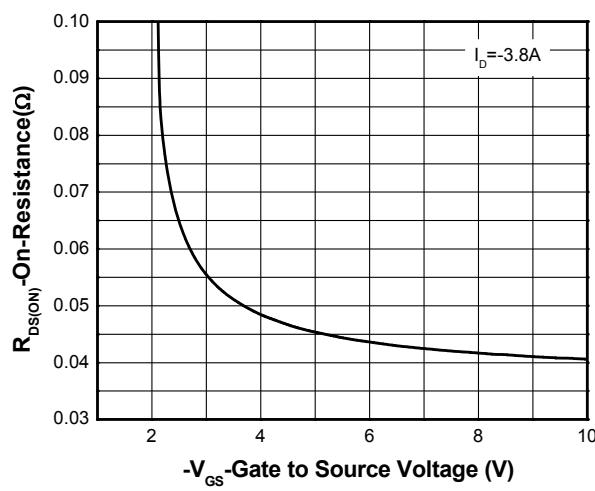
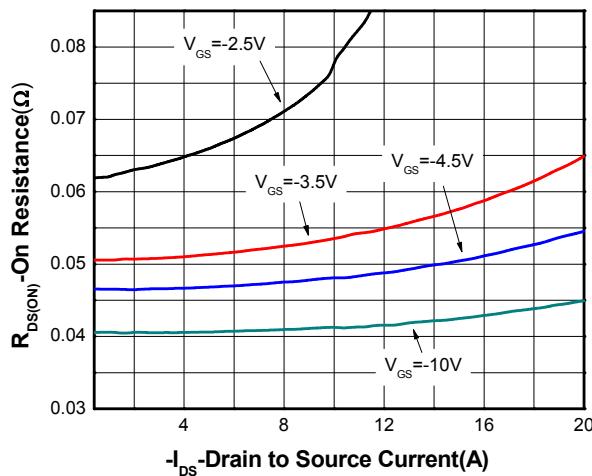
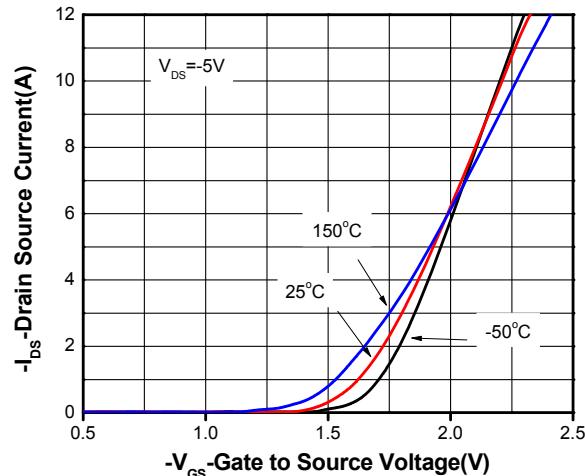
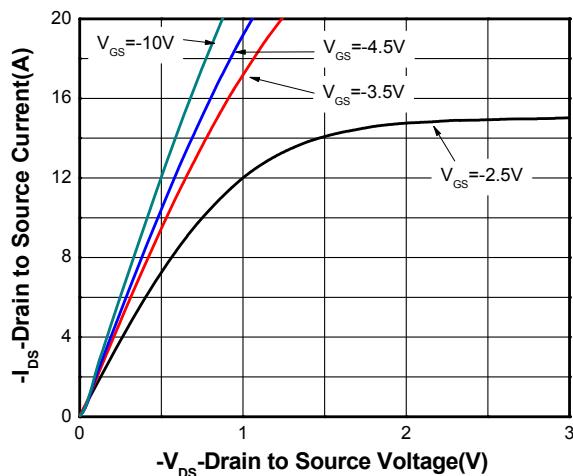
b Surface mounted on FR4 board using minimum pad size, 1oz copper

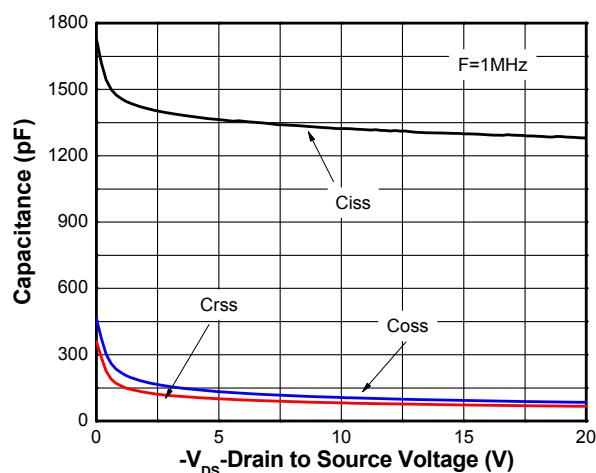
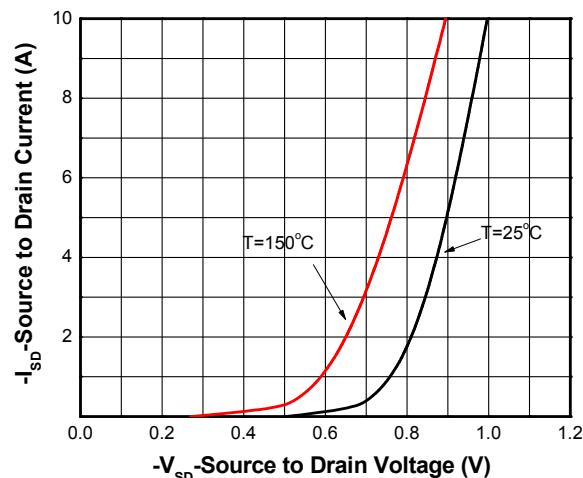
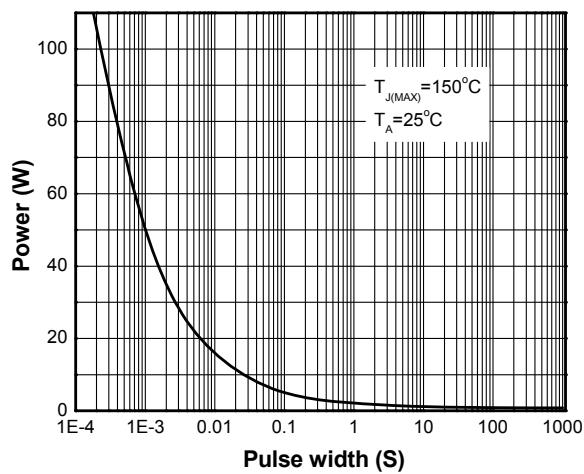
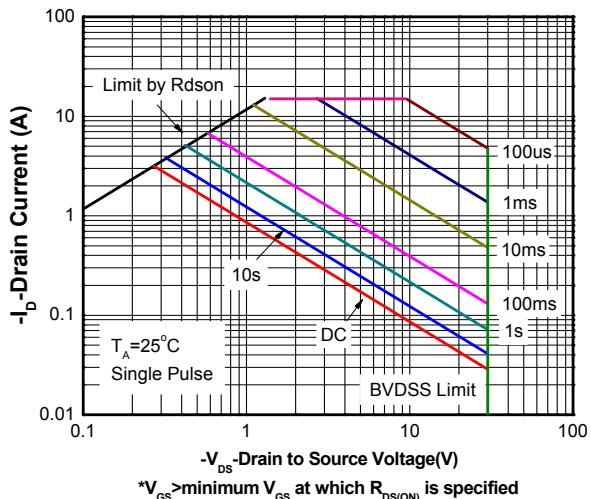
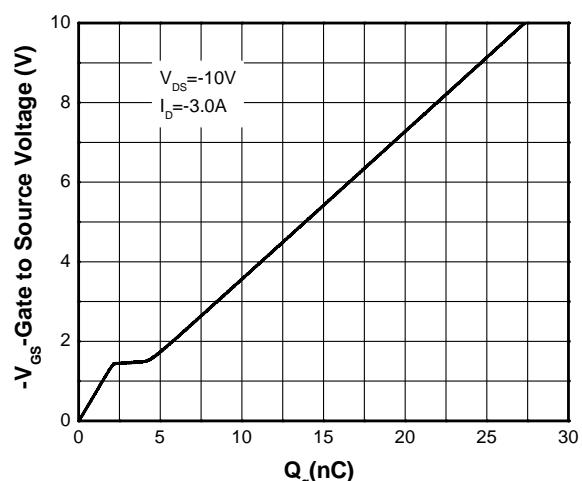
c Repetitive rating, pulse width limited by junction temperature, t_p=10µs, Duty Cycle=1%

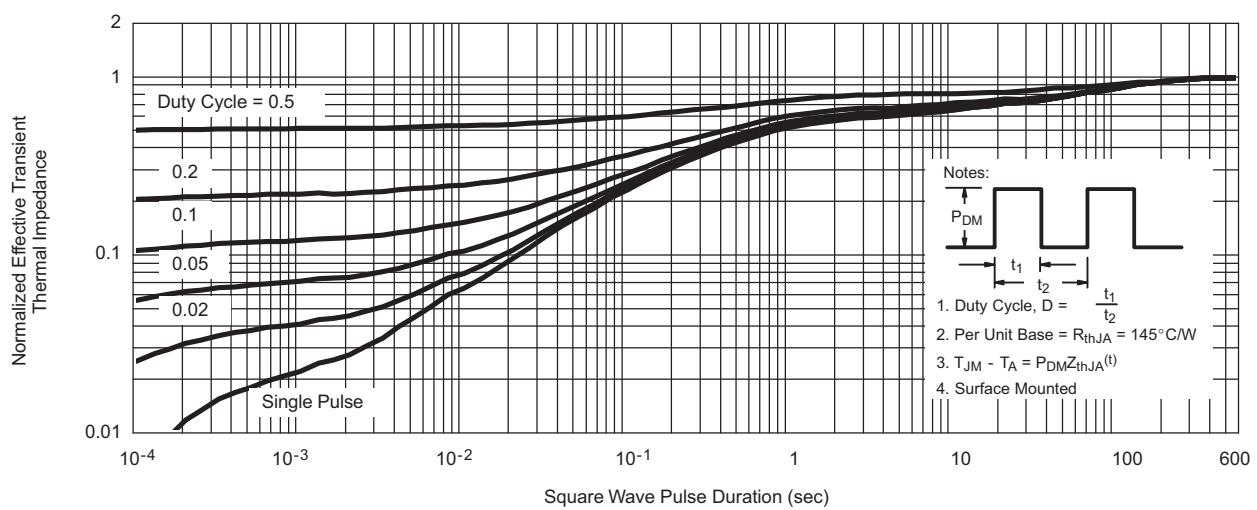
d Repetitive rating, pulse width limited by junction temperature T_J=150°C.

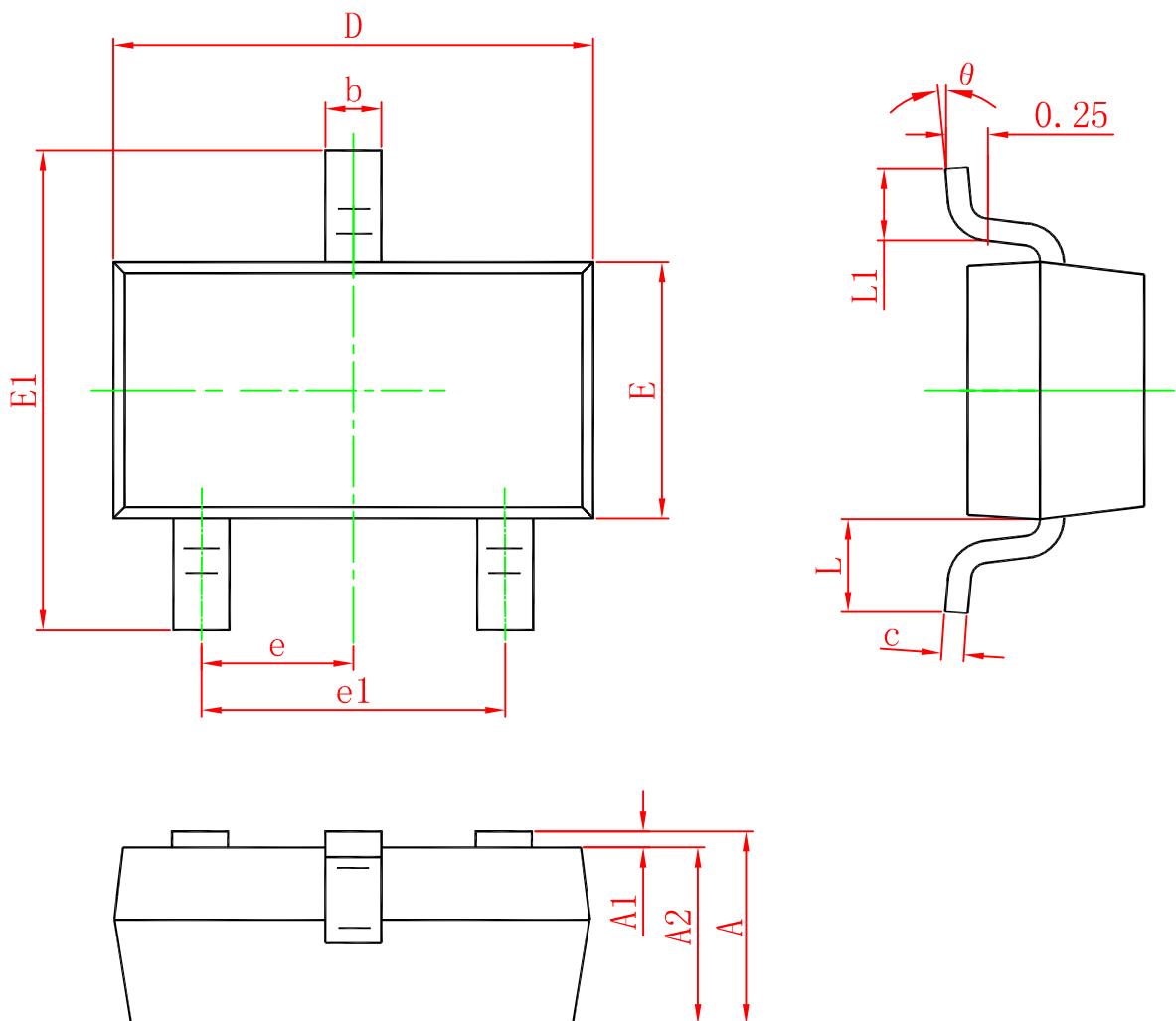
Electronics Characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0 \text{ V}, I_D = -250\mu\text{A}$	-30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -24\text{V}, V_{GS} = 0\text{V}$			-1	μA
Gate-to-source Leakage Current	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12\text{V}$			± 100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	$V_{GS} = V_{DS}, I_D = -250\mu\text{A}$	-0.5	-1.0	-1.5	V
Drain-to-source On-resistance	$R_{DS(\text{on})}$	$V_{GS} = -10\text{V}, I_D = -3.8\text{A}$		43	57	$\text{m}\Omega$
		$V_{GS} = -4.5\text{V}, I_D = -2.5\text{A}$		48	71	
		$V_{GS} = -2.5\text{V}, I_D = -2.0\text{A}$		65	115	
Forward Transconductance	g_{FS}	$V_{DS} = -5 \text{ V}, I_D = -3.8\text{A}$		6	16	S
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C_{ISS}	$V_{GS} = 0 \text{ V}, f = 1.0\text{MHz}, V_{DS} = -15 \text{ V}$		1300		pF
Output Capacitance	C_{OSS}			93		
Reverse Transfer Capacitance	C_{RSS}			73		
Total Gate Charge	$Q_{G(\text{TOT})}$	$V_{GS} = -10 \text{ V}, V_{DS} = -10 \text{ V}, I_D = -3.0 \text{ A}$		27		nC
Threshold Gate Charge	$Q_{G(\text{TH})}$			1.1		
Gate-to-Source Charge	Q_{GS}			2.2		
Gate-to-Drain Charge	Q_{GD}			2.0		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	$td(\text{ON})$	$V_{GS} = -10 \text{ V}, V_{DS} = -15 \text{ V}, I_D = -2\text{A}, R_G = 6\Omega$		11		ns
Rise Time	tr			4.4		
Turn-Off Delay Time	$td(\text{OFF})$			78.8		
Fall Time	tf			6		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V_{SD}	$V_{GS} = 0 \text{ V}, I_S = -1\text{A}$		-0.8	-1.5	V

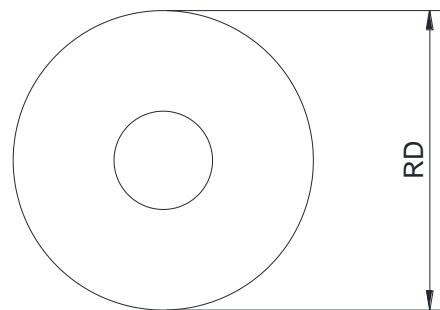
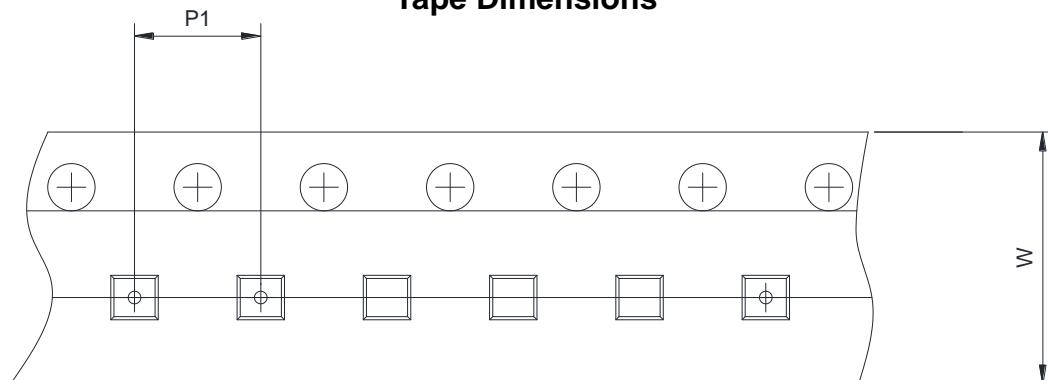
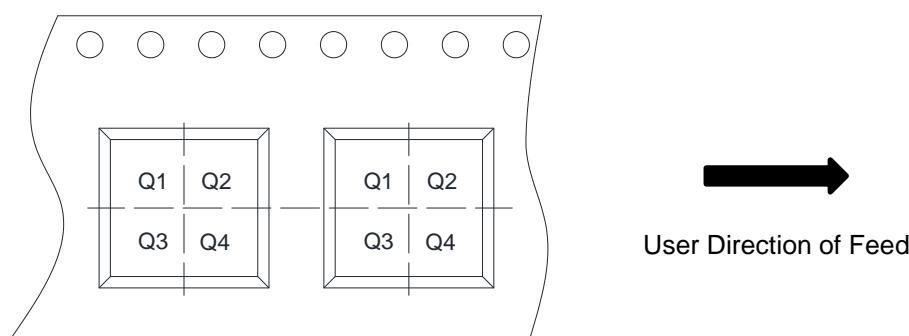
Typical Characteristics (Ta=25°C, unless otherwise noted)



Capacitance

Body diode forward voltage

Single pulse power

Safe operating power

Gate Charge Characteristics

Transient thermal response (Junction-to-Ambient)


Package outline dimensions
SOT-23


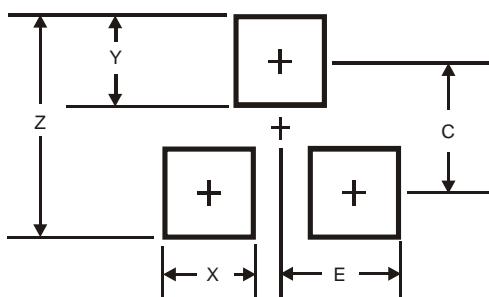
Symbol	Dimensions In Millimeters	
	Min.	Max.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950 (Typ.)	
e1	1.800	2.000
L	0.550 (Typ.)	
L1	0.300	0.500
θ	0°	8°

TAPE AND REEL INFORMATION
Reel Dimensions

Tape Dimensions

Quadrant Assignments For PIN1 Orientation In Tape


RD	Reel Dimension	<input checked="" type="checkbox"/> 7inch	<input type="checkbox"/> 13inch
W	Overall width of the carrier tape	<input checked="" type="checkbox"/> 8mm	<input type="checkbox"/> 12mm <input type="checkbox"/> 16mm
P1	Pitch between successive cavity centers	<input type="checkbox"/> 2mm	<input checked="" type="checkbox"/> 4mm <input type="checkbox"/> 8mm
Pin1	Pin1 Quadrant	<input type="checkbox"/> Q1	<input type="checkbox"/> Q2 <input checked="" type="checkbox"/> Q3 <input type="checkbox"/> Q4

Suggested Land Pattern

SOT-23



Dimensions	Value (mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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